# mail

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Kind regards,

Team Nexperia

PNP resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

Rev. 02 — 3 September 2009

Product data sheet

#### **Product profile** 1.

### 1.1 General description

PNP Resistor-Equipped Transistors (RET) family.

#### Table 1. **Product overview**

Type number	Package	Package				
	NXP	JEITA	JEDEC			
PDTA123TE	SOT416	SC-75	-	PDTC123TE		
PDTA123TK	SOT346	SC-59A	TO-236	PDTC123TK		
PDTA123TM	SOT883	SC-101	-	PDTC123TM		
PDTA123TS <sup>[1]</sup>	SOT54	SC-43A	TO-92	PDTC123TS		
PDTA123TT	SOT23	-	TO-236AB	PDTC123TT		
PDTA123TU	SOT323	SC-70	-	PDTC123TU		

[1] Also available in SOT54A and SOT54 variant packages (see Section 2)

#### 1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability

### 1.3 Applications

- Digital applications
- Controlling IC inputs

#### **1.4 Quick reference data**

### . . .

Table 2.	Quick reference data					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-50	V
I <sub>O</sub>	output current		-	-	-100	mA
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ



Reduces component count

- Reduces pick and place costs
- Cost-saving alternative for BC857 series in digital applications
- Switching loads

PNP resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

### 2. Pinning information

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		
3	GND (emitter)		1 R1 3 006aaa217
SOT54A			
1	input (base)		
2	output (collector)		
3	GND (emitter)	1 2 001aab348	1 R1 006aaa217
SOT54 va	riant		
1	input (base)		
2	output (collector)		
3	GND (emitter)	Cm Cm D D D D D D D D D D D D D D D D D	1 R1 3 006aaa217
SOT23; S	OT323; SOT346; SOT416		
1	input (base)		
2	GND (emitter)	3	
3	output (collector)	1 2 006aaa144	1 R1 z sym009
SOT883			
1	input (base)		
2	GND (emitter)		
3	output (collector)	2 Transparent top view	1 R1 2 sym009

### PNP resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

### 3. Ordering information

ring inform	ation					
Package	age					
Name	Description	Version				
SC-75	plastic surface mounted package; 3 leads	SOT416				
SC-59A	plastic surface mounted package; 3 leads	SOT346				
SC-101	leadless ultra small plastic package; 3 solder lands; body $1.0\times0.6\times0.5$ mm	SOT883				
SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
-	plastic surface mounted package; 3 leads	SOT23				
SC-70	plastic surface mounted package; 3 leads	SOT323				
	Package         Name         SC-75         SC-59A         SC-101         SC-43A	Name       Description         SC-75       plastic surface mounted package; 3 leads         SC-59A       plastic surface mounted package; 3 leads         SC-101       leadless ultra small plastic package; 3 solder lands; body 1.0 × 0.6 × 0.5 mm         SC-43A       plastic single-ended leaded (through hole) package; 3 leads         -       plastic surface mounted package; 3 leads				

[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9)

### 4. Marking

Table 5. Marking codes	
Type number	Marking code <sup>[1]</sup>
PDTA123TE	2A
PDTA123TK	GA
PDTA123TM	FA
PDTA123TS	TA123T
PDTA123TT	ZL*
PDTA123TU	*1S

[1] \* = -: made in Hong Kong

\* = p: made in Hong Kong

\* = t: made in Malaysia

\* = W: made in China

#### PNP resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = open

### 5. Limiting values

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
lo	output current			-	-100	mA
I <sub>CM</sub>	peak collector current	single pulse; $t_p \leq 1 ms$		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$				
	SOT416		<u>[1]</u>	-	150	mW
	SOT346		<u>[1]</u>	-	250	mW
	SOT883		[2][3]	-	250	mW
	SOT54		<u>[1]</u>	-	500	mW
	SOT23		<u>[1]</u>	-	250	mW
	SOT323		<u>[1]</u>	-	200	mW
T <sub>stg</sub>	storage temperature			-65	+150	°C
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 60  $\mu$ m copper strip line, standard footprint.

### 6. Thermal characteristics

Table 7.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> _	-	833	K/W
	SOT346		<u>[1]</u> _	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> _	-	625	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

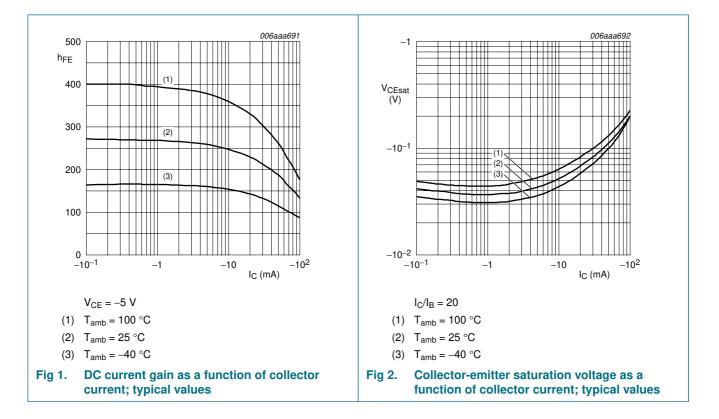
[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 60  $\mu$ m copper strip line, standard footprint.

PNP resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = open

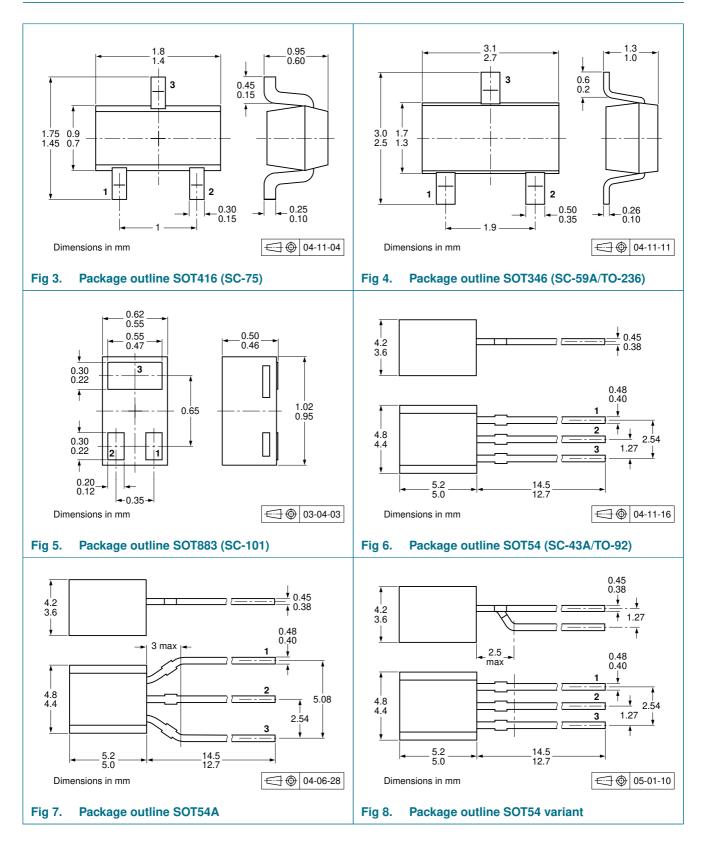
### 7. Characteristics

Table 8. $T_{amb} = 25$	Characteristics °C unless otherwise spec	ified				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; \text{ I}_{E} = 0 \text{ A}$	-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A}$	-	-	-1	μA
	current	$\label{eq:VCE} \begin{array}{l} V_{CE} = -30 \ V; \ I_B = 0 \ A; \\ T_j = 150 \ ^\circ C \end{array}$	-	-	-50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -20 \text{ mA}$	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_{C} = -10 \text{ mA}; I_{B} = -0.5 \text{ mA}$	-	-	-150	mV
R1	bias resistor 1 (input)		1.54	2.2	2.86	kΩ
C <sub>c</sub>	collector capacitance	$\label{eq:VCB} \begin{split} V_{CB} = -10 \ V; \ I_E = i_e = 0 \ A; \\ f = 1 \ MHz \end{split}$	-	-	3	pF

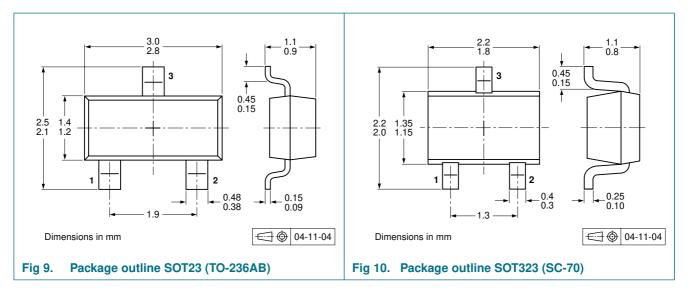


PNP resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = open

### 8. Package outline



PNP resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = open



### 9. Packing information

#### Table 9.Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packin	Packing quantity		
			3000	5000	10000	
PDTA123TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA123TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA123TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTA123TS	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide pitch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	
PDTA123TT	SOT23	4 mm pitch, 8 mm tape and reel	-215		-235	
PDTA123TU	SOT323	4 mm pitch, 8 mm tape and reel	-115		-135	

[1] For further information and the availability of packing methods, see Section 12.

PNP resistor-equipped transistors; R1 = 2.2 kΩ, R2 = open

### 10. Revision history

Table 10. Revision hi	story			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PDTA123T_SER_2	20090903	Product data sheet	-	PDTA123T_SER_1
Modifications:		eet was changed to reflect w legal definitions and disc		
PDTA123T_SER_1	20060307	Product data sheet	-	-

### **11. Legal information**

### 11.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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#### **NXP Semiconductors**

### **PDTA123T series**

PNP resistor-equipped transistors; R1 = 2.2 k $\Omega$ , R2 = open

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